Diode Semiconductor Device - Page 1 of 1



open

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Inclosure Material:
Plastic
Function For Which Designed:
Switching
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-18
Electrode Internally-electrically Connected To Case:
Collector
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 breakdown voltage, collector-to-base, emitter open and 4.5 breakdown voltage, emitter-to-base, collector of
Current Rating Per Characteristic:
500.00 microamperes source cutoff current
Power Rating Per Characteristic:
1.2 watts small-signal input power, common-collector preset
Capacitance Rating In Picofarads:
4.0
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0